NSN 5961-01-196-4898

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View Online at https://aerobasegroup.com/nsn/5961-01-196-4898 **Inclosure Material:** Metal **Overall Length:** 1.330 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-61 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to base voltage/static/emitter open and 9.0 emitter to base voltage, static, collector open and 400.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** Between 10.00 amperes source cutoff current and 5.00 amperes source cutoff current and 15.00 amperes source cutoff current blank **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 35.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 wire hook Shelf Life:

Demilitarization:

Unit Of Measure:

No

N/a

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